



Docket No. 008089 USA/MTCG/PCTRL

PATENT/OFFICIAL

IPR

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Rahul SURANA et al.

Serial No. 10/809,906

: Group Art Unit: 3723

Filed: March 26, 2004

: Examiner:

For: A TECHNIQUE FOR PROCESS-QUALIFYING A SEMICONDUCTOR  
MANUFACTURING TOOL USING METROLOGY DATA

**SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT**

Honorable Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the documents listed on the attached form PTO-1449. It is respectfully requested that the documents be expressly considered during the prosecution of this application, and that the documents be made of record therein and appear among the "References Cited" on any patent to issue therefrom. Copies of any cited U.S. Patents and U.S. Patent Publications are not being submitted in accordance with 37 CFR 1.98(a)(2)(i).

This Information Disclosure Statement is being filed within three months of the U.S. filing date OR before the mailing date of a first Office Action on the merits. No certification or fee is required.

In accordance with 37 C.F.R. § 1.97(g) and (h), the filing of this IDS should not be construed as a representation that a search had been made or that information cited is, or is considered to be, material to patentability as defined in 37 C.F.R. § 1.56 (b), or that any cited document listed or attached is (or constitutes) prior art. Unless otherwise indicated, the date of

publication indicated for an item is taken from the face of the item, and Applicant reserves the right to prove that the date of publication is in fact different.

No fee is believed to be required; however, the Commissioner is authorized to charge any deficiency in any fees pursuant to 37 CFR § 1.17 associated with this communication and to credit any excess payment to Deposit Account No. 08-0219.

Respectfully submitted,

WILMER CUTLER PICKERING HALE AND DORR LLP



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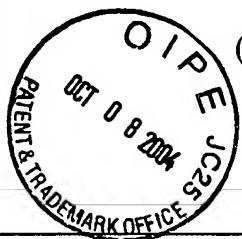
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<p style="text-align: center;">INFORMATION DISCLOSURE CITATION IN AN APPLICATION (PTO-1449)</p> <p>O P E OCT 08 2004 JC25 PATENT &amp; TRADEMARK OFFICE</p>		ATTY. DOCKET NO. 008089 USA/ MTCG/PCTRL	SERIAL NO. 10/809,906			
<p>APPLICANT Rahul SURANA et al.</p>						
<p>FILING DATE March 26, 2004</p>		<p>GROUP 3723</p>				
<b>U.S. PATENT DOCUMENTS</b>						
EXAMINER'S INITIALS	PATENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE
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	6,725,402 B1	04/20/04	Coss, Jr. et al.			07/31/00
EXAMINER			DATE CONSIDERED			

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.

INFORMATION DISCLOSURE  
CITATION IN AN  
APPLICATION

(PTO-1449)



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APPLICANT  
Rahul SURANA et al.

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	Kim, Eui Jung and William N. Gill. July 1994. "Analytical Model for Chemical Vapor Deposition of SiO <sub>2</sub> Films Using Tetraethoxysilane and Ozone" (Abstract). <i>Journal of Crystal Growth</i> , Vol. 140, Issues 3-4, pp. 315-326.
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EXAMINER	DATE CONSIDERED

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